VERSION SHOWING AMENDMENTS TO THE CLAIMS

This listing replaces all prior listings of the claims.

Claims:

Amend the claims as follows:

1 (Currently amended) <u>In an electronic organic component, the combination</u> comprising:

[[A]] <u>a</u> substrate and/or underlayer of <u>the an</u> electronic component;[[,]] <u>and</u>

which substrate or underlayer is to be coated with an <u>an</u> organic <u>semiconductor</u>

functional layer <u>coated on the substrate or underlayer[[,]];</u>

wherein said substrate or underlayer comprises a biaxially stretched (well-ordered) plastic film such that the orderliness of the plastic film enables the application of forms the applied functional layer material thereto into the form of a well-ordered layer to thereby increase the charge carrier mobility of the coated organic functional layer.

2 (Previously presented) A substrate as defined in claim 1, wherein the plastic film is at least partially crystalline.

Claim 3, canceled

- 4 (Currently amended). A substrate as defined in claims <u>1-3-1 and 2</u>, wherein the plastic film is selected from any one of the group consisting of isotactic polypropylene, polyamide, polyethylene, or polyethylene terephthalate.
- 5 (Currently amended) A method of increasing the charge carrier mobility of a conducting or semiconducting layer of organic material, wherein the conducting or semiconducting layer is formed on an underlayer comprising an oriented, biaxially stretched (well-ordered) plastic film.
- 6 (Currently amended) The component of any one of claims 1 and 2 wherein the component further comprises An an organic field effect transistor (OFET) comprising the substrate or an underlayer and the [[a]] semiconductoring layer coated on the substrate or underlayer according to any one of claims 1 to 3.
- 7 (Currently amended). An organic field effect transistor (OFET) comprising:

 a substrate or an underlayer which comprises a biaxially stretched (well-ordered plastic film); and

above and on that substrate or underlayer <u>is a semiconducting layer of organic</u> material, the semiconductor layer exhibiting a charge carrier mobility of μ >10⁻³ cm²/Vs.

Claim 8, canceled.

9 (Currently amended) An <u>organic field effect transistor (OFET)</u> comprising an underlayer and a semiconducting layer on the underlayer according to claim 4.